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### Understanding [Embedded - CPLDs \(Complex Programmable Logic Devices\)](#)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

### Applications of Embedded - CPLDs

#### Details

Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	16
Number of Macrocells	256
Number of Gates	5000
Number of I/O	84
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/intel/epm7256aetc100-7n">https://www.e-xfl.com/product-detail/intel/epm7256aetc100-7n</a>

**Table 1. MAX 7000A Device Features**

Feature	EPM7032AE	EPM7064AE	EPM7128AE	EPM7256AE	EPM7512AE
Usable gates	600	1,250	2,500	5,000	10,000
Macrocells	32	64	128	256	512
Logic array blocks	2	4	8	16	32
Maximum user I/O pins	36	68	100	164	212
$t_{PD}$ (ns)	4.5	4.5	5.0	5.5	7.5
$t_{SU}$ (ns)	2.9	2.8	3.3	3.9	5.6
$t_{FSU}$ (ns)	2.5	2.5	2.5	2.5	3.0
$t_{CO1}$ (ns)	3.0	3.1	3.4	3.5	4.7
$f_{CNT}$ (MHz)	227.3	222.2	192.3	172.4	116.3

## ...and More Features

- 4.5-ns pin-to-pin logic delays with counter frequencies of up to 227.3 MHz
- MultiVolt™ I/O interface enables device core to run at 3.3 V, while I/O pins are compatible with 5.0-V, 3.3-V, and 2.5-V logic levels
- Pin counts ranging from 44 to 256 in a variety of thin quad flat pack (TQFP), plastic quad flat pack (PQFP), ball-grid array (BGA), space-saving FineLine BGA™, and plastic J-lead chip carrier (PLCC) packages
- Supports hot-socketing in MAX 7000AE devices
- Programmable interconnect array (PIA) continuous routing structure for fast, predictable performance
- PCI-compatible
- Bus-friendly architecture, including programmable slew-rate control
- Open-drain output option
- Programmable macrocell registers with individual clear, preset, clock, and clock enable controls
- Programmable power-up states for macrocell registers in MAX 7000AE devices
- Programmable power-saving mode for 50% or greater power reduction in each macrocell
- Configurable expander product-term distribution, allowing up to 32 product terms per macrocell
- Programmable security bit for protection of proprietary designs
- 6 to 10 pin- or logic-driven output enable signals
- Two global clock signals with optional inversion
- Enhanced interconnect resources for improved routability
- Fast input setup times provided by a dedicated path from I/O pin to macrocell registers
- Programmable output slew-rate control
- Programmable ground pins

## Functional Description

The MAX 7000A architecture includes the following elements:

- Logic array blocks (LABs)
- Macrocells
- Expander product terms (shareable and parallel)
- Programmable interconnect array
- I/O control blocks

The MAX 7000A architecture includes four dedicated inputs that can be used as general-purpose inputs or as high-speed, global control signals (clock, clear, and two output enable signals) for each macrocell and I/O pin. [Figure 1](#) shows the architecture of MAX 7000A devices.

For registered functions, each macrocell flipflop can be individually programmed to implement D, T, JK, or SR operation with programmable clock control. The flipflop can be bypassed for combinatorial operation. During design entry, the designer specifies the desired flipflop type; the Altera software then selects the most efficient flipflop operation for each registered function to optimize resource utilization.

Each programmable register can be clocked in three different modes:

- Global clock signal. This mode achieves the fastest clock-to-output performance.
- Global clock signal enabled by an active-high clock enable. A clock enable is generated by a product term. This mode provides an enable on each flipflop while still achieving the fast clock-to-output performance of the global clock.
- Array clock implemented with a product term. In this mode, the flipflop can be clocked by signals from buried macrocells or I/O pins.

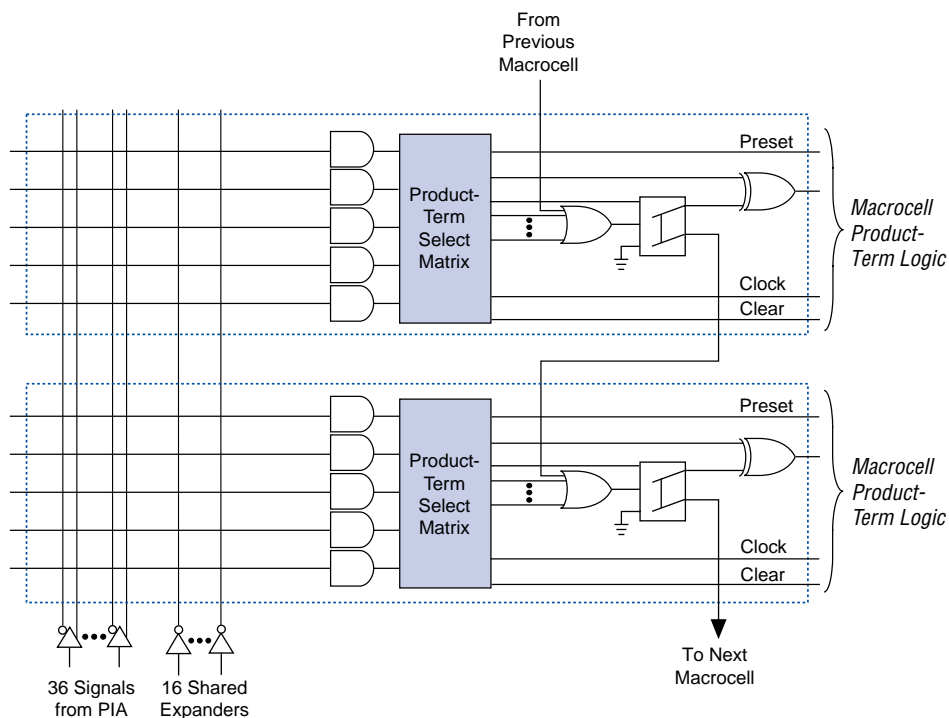
Two global clock signals are available in MAX 7000A devices. As shown in [Figure 1](#), these global clock signals can be the true or the complement of either of the global clock pins, GCLK1 or GCLK2.

Each register also supports asynchronous preset and clear functions. As shown in [Figure 2](#), the product-term select matrix allocates product terms to control these operations. Although the product-term-driven preset and clear from the register are active high, active-low control can be obtained by inverting the signal within the logic array. In addition, each register clear function can be individually driven by the active-low dedicated global clear pin (GCLRn). Upon power-up, each register in a MAX 7000AE device may be set to either a high or low state. This power-up state is specified at design entry. Upon power-up, each register in EPM7128A and EPM7256A devices are set to a low state.

All MAX 7000A I/O pins have a fast input path to a macrocell register. This dedicated path allows a signal to bypass the PIA and combinatorial logic and be clocked to an input D flipflop with an extremely fast (as low as 2.5 ns) input setup time.

**Figure 4. MAX 7000A Parallel Expanders**

*Unused product terms in a macrocell can be allocated to a neighboring macrocell.*



## Programmable Interconnect Array

Logic is routed between LABs on the PIA. This global bus is a programmable path that connects any signal source to any destination on the device. All MAX 7000A dedicated inputs, I/O pins, and macrocell outputs feed the PIA, which makes the signals available throughout the entire device. Only the signals required by each LAB are actually routed from the PIA into the LAB. Figure 5 shows how the PIA signals are routed into the LAB. An EEPROM cell controls one input to a 2-input AND gate, which selects a PIA signal to drive into the LAB.



For more information on using the Jam STAPL language, see *Application Note 88 (Using the Jam Language for ISP & ICR via an Embedded Processor)* and *Application Note 122 (Using Jam STAPL for ISP & ICR via an Embedded Processor)*.

ISP circuitry in MAX 7000AE devices is compliant with the IEEE Std. 1532 specification. The IEEE Std. 1532 is a standard developed to allow concurrent ISP between multiple PLD vendors.

## Programming Sequence

During in-system programming, instructions, addresses, and data are shifted into the MAX 7000A device through the TDI input pin. Data is shifted out through the TDO output pin and compared against the expected data.

Programming a pattern into the device requires the following six ISP stages. A stand-alone verification of a programmed pattern involves only stages 1, 2, 5, and 6.

1. *Enter ISP.* The enter ISP stage ensures that the I/O pins transition smoothly from user mode to ISP mode. The enter ISP stage requires 1 ms.
2. *Check ID.* Before any program or verify process, the silicon ID is checked. The time required to read this silicon ID is relatively small compared to the overall programming time.
3. *Bulk Erase.* Erasing the device in-system involves shifting in the instructions to erase the device and applying one erase pulse of 100 ms.
4. *Program.* Programming the device in-system involves shifting in the address and data and then applying the programming pulse to program the EEPROM cells. This process is repeated for each EEPROM address.
5. *Verify.* Verifying an Altera device in-system involves shifting in addresses, applying the read pulse to verify the EEPROM cells, and shifting out the data for comparison. This process is repeated for each EEPROM address.
6. *Exit ISP.* An exit ISP stage ensures that the I/O pins transition smoothly from ISP mode to user mode. The exit ISP stage requires 1 ms.

## Programming Times

The time required to implement each of the six programming stages can be broken into the following two elements:

- A pulse time to erase, program, or read the EEPROM cells.
- A shifting time based on the test clock (TCK) frequency and the number of TCK cycles to shift instructions, address, and data into the device.

By combining the pulse and shift times for each of the programming stages, the program or verify time can be derived as a function of the TCK frequency, the number of devices, and specific target device(s). Because different ISP-capable devices have a different number of EEPROM cells, both the total fixed and total variable times are unique for a single device.

### *Programming a Single MAX 7000A Device*

The time required to program a single MAX 7000A device in-system can be calculated from the following formula:

$$t_{PROG} = t_{PPULSE} + \frac{Cycle_{PTCK}}{f_{TCK}}$$

where:  $t_{PROG}$  = Programming time  
 $t_{PPULSE}$  = Sum of the fixed times to erase, program, and verify the EEPROM cells  
 $Cycle_{PTCK}$  = Number of TCK cycles to program a device  
 $f_{TCK}$  = TCK frequency

The ISP times for a stand-alone verification of a single MAX 7000A device can be calculated from the following formula:

$$t_{VER} = t_{VPULSE} + \frac{Cycle_{VTCK}}{f_{TCK}}$$

where:  $t_{VER}$  = Verify time  
 $t_{VPULSE}$  = Sum of the fixed times to verify the EEPROM cells  
 $Cycle_{VTCK}$  = Number of TCK cycles to verify a device

**Table 8. MAX 7000A JTAG Instructions**

JTAG Instruction	Description
SAMPLE/PRELOAD	Allows a snapshot of signals at the device pins to be captured and examined during normal device operation, and permits an initial data pattern output at the device pins
EXTEST	Allows the external circuitry and board-level interconnections to be tested by forcing a test pattern at the output pins and capturing test results at the input pins
BYPASS	Places the 1-bit bypass register between the TDI and TDO pins, which allows the BST data to pass synchronously through a selected device to adjacent devices during normal device operation
IDCODE	Selects the IDCODE register and places it between the TDI and TDO pins, allowing the IDCODE to be serially shifted out of TDO
USERCODE	Selects the 32-bit USERCODE register and places it between the TDI and TDO pins, allowing the USERCODE value to be shifted out of TDO. The USERCODE instruction is available for MAX 7000AE devices only
UESCODE	These instructions select the user electronic signature (UESCODE) and allow the UESCODE to be shifted out of TDO. UESCODE instructions are available for EPM7128A and EPM7256A devices only.
ISP Instructions	These instructions are used when programming MAX 7000A devices via the JTAG ports with the MasterBlaster, ByteBlasterMV, or BitBlaster download cable, or using a Jam STAPL File, JBC File, or SVF File via an embedded processor or test equipment.



# Programmable Speed/Power Control

MAX 7000A devices offer a power-saving mode that supports low-power operation across user-defined signal paths or the entire device. This feature allows total power dissipation to be reduced by 50% or more because most logic applications require only a small fraction of all gates to operate at maximum frequency.

The designer can program each individual macrocell in a MAX 7000A device for either high-speed (i.e., with the Turbo Bit™ option turned on) or low-power operation (i.e., with the Turbo Bit option turned off). As a result, speed-critical paths in the design can run at high speed, while the remaining paths can operate at reduced power. Macrocells that run at low power incur a nominal timing delay adder ( $t_{LPA}$ ) for the  $t_{LAD}$ ,  $t_{LAC}$ ,  $t_{IC}$ ,  $t_{EN}$ ,  $t_{SEXP}$ ,  $t_{ACL}$ , and  $t_{CPPW}$  parameters.

# Output Configuration

MAX 7000A device outputs can be programmed to meet a variety of system-level requirements.

## MultiVolt I/O Interface

The MAX 7000A device architecture supports the MultiVolt I/O interface feature, which allows MAX 7000A devices to connect to systems with differing supply voltages. MAX 7000A devices in all packages can be set for 2.5-V, 3.3-V, or 5.0-V I/O pin operation. These devices have one set of VCC pins for internal operation and input buffers (VCCINT), and another set for I/O output drivers (VCCIO).

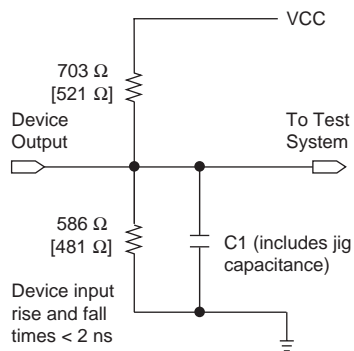
The VCCIO pins can be connected to either a 3.3-V or 2.5-V power supply, depending on the output requirements. When the VCCIO pins are connected to a 2.5-V power supply, the output levels are compatible with 2.5-V systems. When the VCCIO pins are connected to a 3.3-V power supply, the output high is at 3.3 V and is therefore compatible with 3.3-V or 5.0-V systems. Devices operating with VCCIO levels lower than 3.0 V incur a slightly greater timing delay of  $t_{OD2}$  instead of  $t_{OD1}$ . Inputs can always be driven by 2.5-V, 3.3-V, or 5.0-V signals.

Table 12 describes the MAX 7000A MultiVolt I/O support.

Table 12. MAX 7000A MultiVolt I/O Support						
V <sub>CCIO</sub> Voltage	Input Signal (V)			Output Signal (V)		
	2.5	3.3	5.0	2.5	3.3	5.0
2.5	✓	✓	✓	✓		
3.3	✓	✓	✓		✓	✓

**Figure 9. MAX 7000A AC Test Conditions**

Power supply transients can affect AC measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under AC conditions. Large-amplitude, fast-ground-current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, significant reductions in observable noise immunity can result. Numbers in brackets are for 2.5-V outputs. Numbers without brackets are for 3.3-V outputs.



## Operating Conditions

Tables 13 through 16 provide information on absolute maximum ratings, recommended operating conditions, operating conditions, and capacitance for MAX 7000A devices.

**Table 13. MAX 7000A Device Absolute Maximum Ratings** *Note (1)*

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply voltage	With respect to ground (2)	−0.5	4.6	V
V <sub>I</sub>	DC input voltage		−2.0	5.75	V
I <sub>OUT</sub>	DC output current, per pin		−25	25	mA
T <sub>STG</sub>	Storage temperature	No bias	−65	150	°C
T <sub>A</sub>	Ambient temperature	Under bias	−65	135	°C
T <sub>J</sub>	Junction temperature	BGA, FineLine BGA, PQFP, and TQFP packages, under bias		135	°C

**Table 14. MAX 7000A Device Recommended Operating Conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CCINT}$	Supply voltage for internal logic and input buffers	(3), (13)	3.0	3.6	V
$V_{CCIO}$	Supply voltage for output drivers, 3.3-V operation	(3)	3.0	3.6	V
	Supply voltage for output drivers, 2.5-V operation	(3)	2.3	2.7	V
$V_{CCISP}$	Supply voltage during in-system programming		3.0	3.6	V
$V_I$	Input voltage	(4)	−0.5	5.75	V
$V_O$	Output voltage		0	$V_{CCIO}$	V
$T_A$	Ambient temperature	Commercial range	0	70	°C
		Industrial range (5)	−40	85	°C
$T_J$	Junction temperature	Commercial range	0	90	°C
		Industrial range (5)	−40	105	°C
		Extended range (5)	−40	130	°C
$t_R$	Input rise time			40	ns
$t_F$	Input fall time			40	ns

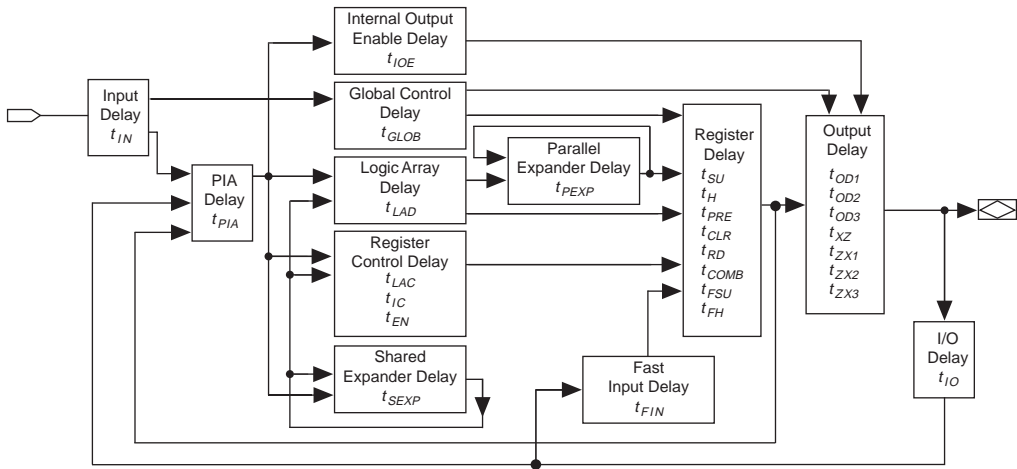
**Table 15. MAX 7000A Device DC Operating Conditions** *Note (6)*

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{IH}$	High-level input voltage		1.7	5.75	V
$V_{IL}$	Low-level input voltage		-0.5	0.8	V
$V_{OH}$	3.3-V high-level TTL output voltage	$I_{OH} = -8$ mA DC, $V_{CCIO} = 3.00$ V (7)	2.4		V
	3.3-V high-level CMOS output voltage	$I_{OH} = -0.1$ mA DC, $V_{CCIO} = 3.00$ V (7)	$V_{CCIO} - 0.2$		V
	2.5-V high-level output voltage	$I_{OH} = -100$ $\mu$ A DC, $V_{CCIO} = 2.30$ V (7)	2.1		V
		$I_{OH} = -1$ mA DC, $V_{CCIO} = 2.30$ V (7)	2.0		V
		$I_{OH} = -2$ mA DC, $V_{CCIO} = 2.30$ V (7)	1.7		V
$V_{OL}$	3.3-V low-level TTL output voltage	$I_{OL} = 8$ mA DC, $V_{CCIO} = 3.00$ V (8)		0.45	V
	3.3-V low-level CMOS output voltage	$I_{OL} = 0.1$ mA DC, $V_{CCIO} = 3.00$ V (8)		0.2	V
	2.5-V low-level output voltage	$I_{OL} = 100$ $\mu$ A DC, $V_{CCIO} = 2.30$ V (8)		0.2	V
		$I_{OL} = 1$ mA DC, $V_{CCIO} = 2.30$ V (8)		0.4	V
		$I_{OL} = 2$ mA DC, $V_{CCIO} = 2.30$ V (8)		0.7	V
$I_I$	Input leakage current	$V_I = -0.5$ to $5.5$ V (9)	-10	10	$\mu$ A
$I_{OZ}$	Tri-state output off-state current	$V_I = -0.5$ to $5.5$ V (9)	-10	10	$\mu$ A
$R_{ISP}$	Value of I/O pin pull-up resistor during in-system programming or during power-up	$V_{CCIO} = 3.0$ to $3.6$ V (10)	20	50	k $\Omega$
		$V_{CCIO} = 2.3$ to $2.7$ V (10)	30	80	k $\Omega$
		$V_{CCIO} = 2.3$ to $3.6$ V (11)	20	74	k $\Omega$

**Table 16. MAX 7000A Device Capacitance** *Note (12)*

Symbol	Parameter	Conditions	Min	Max	Unit
$C_{IN}$	Input pin capacitance	$V_{IN} = 0$ V, $f = 1.0$ MHz		8	pF
$C_{I/O}$	I/O pin capacitance	$V_{OUT} = 0$ V, $f = 1.0$ MHz		8	pF

Figure 11. MAX 7000A Timing Model



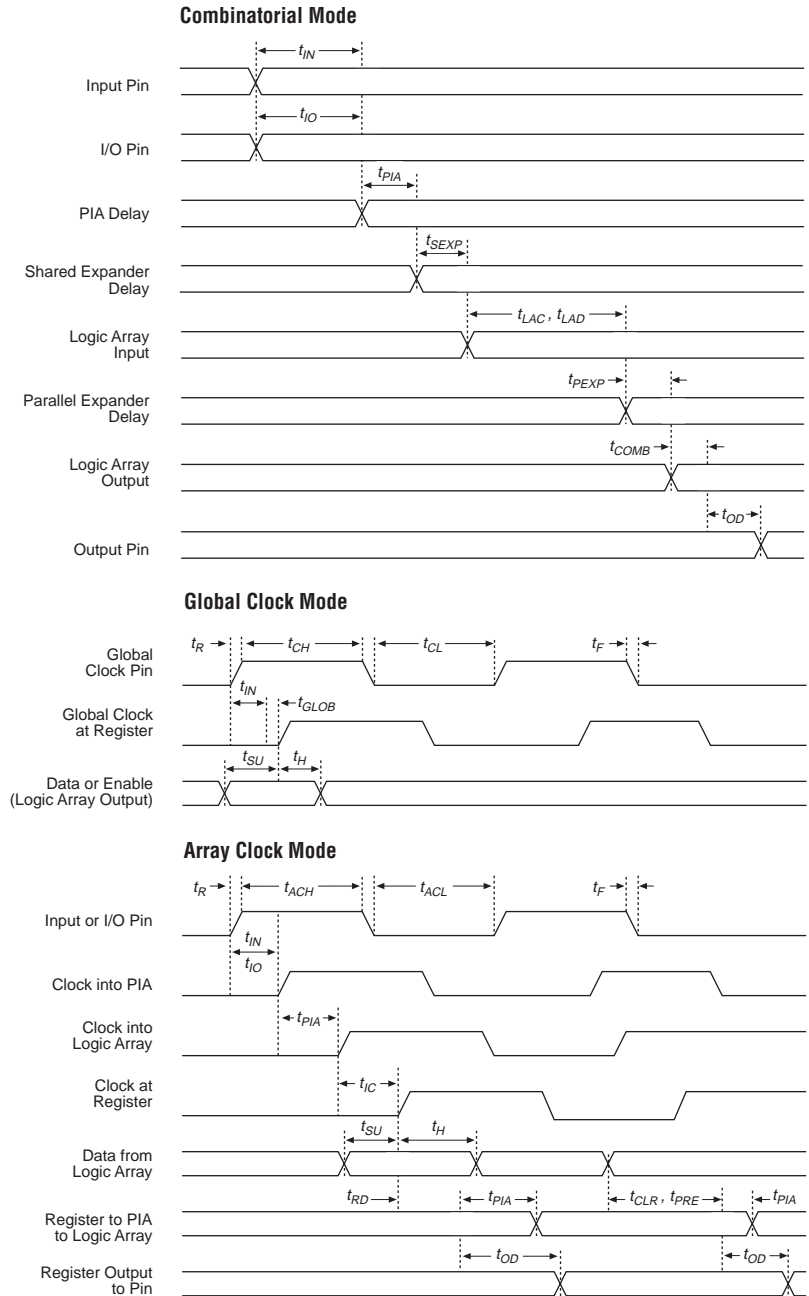
The timing characteristics of any signal path can be derived from the timing model and parameters of a particular device. External timing parameters, which represent pin-to-pin timing delays, can be calculated as the sum of internal parameters. Figure 12 shows the timing relationship between internal and external delay parameters.



See [Application Note 94 \(Understanding MAX 7000 Timing\)](#) for more information.

**Figure 12. MAX 7000A Switching Waveforms**

$t_R$  &  $t_F < 2$  ns. Inputs are driven at 3 V for a logic high and 0 V for a logic low. All timing characteristics are measured at 1.5 V.



Tables 17 through 30 show EPM7032AE, EPM7064AE, EPM7128AE, EPM7256AE, EPM7512AE, EPM7128A, and EPM7256A timing information.

**Table 17. EPM7032AE External Timing Parameters** *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-4		-7		-10		
			Min	Max	Min	Max	Min	Max	
t <sub>PD1</sub>	Input to non-registered output	C1 = 35 pF (2)		4.5		7.5		10	ns
t <sub>PD2</sub>	I/O input to non-registered output	C1 = 35 pF (2)		4.5		7.5		10	ns
t <sub>SU</sub>	Global clock setup time	(2)	2.9		4.7		6.3		ns
t <sub>H</sub>	Global clock hold time	(2)	0.0		0.0		0.0		ns
t <sub>FSU</sub>	Global clock setup time of fast input		2.5		3.0		3.0		ns
t <sub>FH</sub>	Global clock hold time of fast input		0.0		0.0		0.0		ns
t <sub>CO1</sub>	Global clock to output delay	C1 = 35 pF	1.0	3.0	1.0	5.0	1.0	6.7	ns
t <sub>CH</sub>	Global clock high time		2.0		3.0		4.0		ns
t <sub>CL</sub>	Global clock low time		2.0		3.0		4.0		ns
t <sub>ASU</sub>	Array clock setup time	(2)	1.6		2.5		3.6		ns
t <sub>AH</sub>	Array clock hold time	(2)	0.3		0.5		0.5		ns
t <sub>ACO1</sub>	Array clock to output delay	C1 = 35 pF (2)	1.0	4.3	1.0	7.2	1.0	9.4	ns
t <sub>ACH</sub>	Array clock high time		2.0		3.0		4.0		ns
t <sub>ACL</sub>	Array clock low time		2.0		3.0		4.0		ns
t <sub>CPPW</sub>	Minimum pulse width for clear and preset	(3)	2.0		3.0		4.0		ns
t <sub>CNT</sub>	Minimum global clock period	(2)		4.4		7.2		9.7	ns
f <sub>CNT</sub>	Maximum internal global clock frequency	(2), (4)	227.3		138.9		103.1		MHz
t <sub>ACNT</sub>	Minimum array clock period	(2)		4.4		7.2		9.7	ns
f <sub>ACNT</sub>	Maximum internal array clock frequency	(2), (4)	227.3		138.9		103.1		MHz

**Table 20. EPM7064AE Internal Timing Parameters (Part 2 of 2)** *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-4		-7		-10		
			Min	Max	Min	Max	Min	Max	
$t_{EN}$	Register enable time			0.6		1.0		1.2	ns
$t_{GLOB}$	Global control delay			1.0		1.5		2.2	ns
$t_{PRE}$	Register preset time			1.3		2.1		2.9	ns
$t_{CLR}$	Register clear time			1.3		2.1		2.9	ns
$t_{PIA}$	PIA delay	(2)		1.0		1.7		2.3	ns
$t_{LPA}$	Low-power adder	(6)		3.5		4.0		5.0	ns



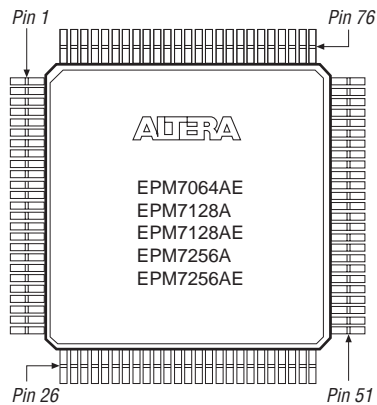
**Table 22. EPM7128AE Internal Timing Parameters (Part 1 of 2)** *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-5		-7		-10		
			Min	Max	Min	Max	Min	Max	
$t_{IN}$	Input pad and buffer delay			0.7		1.0		1.4	ns
$t_{IO}$	I/O input pad and buffer delay			0.7		1.0		1.4	ns
$t_{FIN}$	Fast input delay			2.5		3.0		3.4	ns
$t_{SEXP}$	Shared expander delay			2.0		2.9		3.8	ns
$t_{PEXP}$	Parallel expander delay			0.4		0.7		0.9	ns
$t_{LAD}$	Logic array delay			1.6		2.4		3.1	ns
$t_{LAC}$	Logic control array delay			0.7		1.0		1.3	ns
$t_{IOE}$	Internal output enable delay			0.0		0.0		0.0	ns
$t_{OD1}$	Output buffer and pad delay, slow slew rate = off $V_{CCIO} = 3.3\text{ V}$	$C1 = 35\text{ pF}$		0.8		1.2		1.6	ns
$t_{OD2}$	Output buffer and pad delay, slow slew rate = off $V_{CCIO} = 2.5\text{ V}$	$C1 = 35\text{ pF}$ (5)		1.3		1.7		2.1	ns
$t_{OD3}$	Output buffer and pad delay, slow slew rate = on $V_{CCIO} = 2.5\text{ V}$ or $3.3\text{ V}$	$C1 = 35\text{ pF}$		5.8		6.2		6.6	ns
$t_{ZX1}$	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 3.3\text{ V}$	$C1 = 35\text{ pF}$		4.0		4.0		5.0	ns
$t_{ZX2}$	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 2.5\text{ V}$	$C1 = 35\text{ pF}$ (5)		4.5		4.5		5.5	ns
$t_{ZX3}$	Output buffer enable delay, slow slew rate = on $V_{CCIO} = 3.3\text{ V}$	$C1 = 35\text{ pF}$		9.0		9.0		10.0	ns
$t_{XZ}$	Output buffer disable delay	$C1 = 5\text{ pF}$		4.0		4.0		5.0	ns
$t_{SU}$	Register setup time		1.4		2.1		2.9		ns
$t_H$	Register hold time		0.6		1.0		1.3		ns
$t_{FSU}$	Register setup time of fast input		1.1		1.6		1.6		ns
$t_{FH}$	Register hold time of fast input		1.4		1.4		1.4		ns
$t_{RD}$	Register delay			0.8		1.2		1.6	ns
$t_{COMB}$	Combinatorial delay			0.5		0.9		1.3	ns
$t_{IC}$	Array clock delay			1.2		1.7		2.2	ns

**Table 26. EPM7512AE Internal Timing Parameters (Part 2 of 2)** *Note (1)*

Symbol	Parameter	Conditions	Speed Grade						Unit
			-7		-10		-12		
			Min	Max	Min	Max	Min	Max	
$t_{IC}$	Array clock delay			1.8		2.3		2.9	ns
$t_{EN}$	Register enable time			1.0		1.3		1.7	ns
$t_{GLOB}$	Global control delay			1.7		2.2		2.7	ns
$t_{PRE}$	Register preset time			1.0		1.4		1.7	ns
$t_{CLR}$	Register clear time			1.0		1.4		1.7	ns
$t_{PIA}$	PIA delay	(2)		3.0		4.0		4.8	ns
$t_{LPA}$	Low-power adder	(6)		4.5		5.0		5.0	ns



**Figure 17. 100-Pin TQFP Package Pin-Out Diagram***Package outline not drawn to scale.***Figure 18. 100-Pin FineLine BGA Package Pin-Out Diagram***Package outline not drawn to scale.*